

Etapas amplificadoras básicas con BJT

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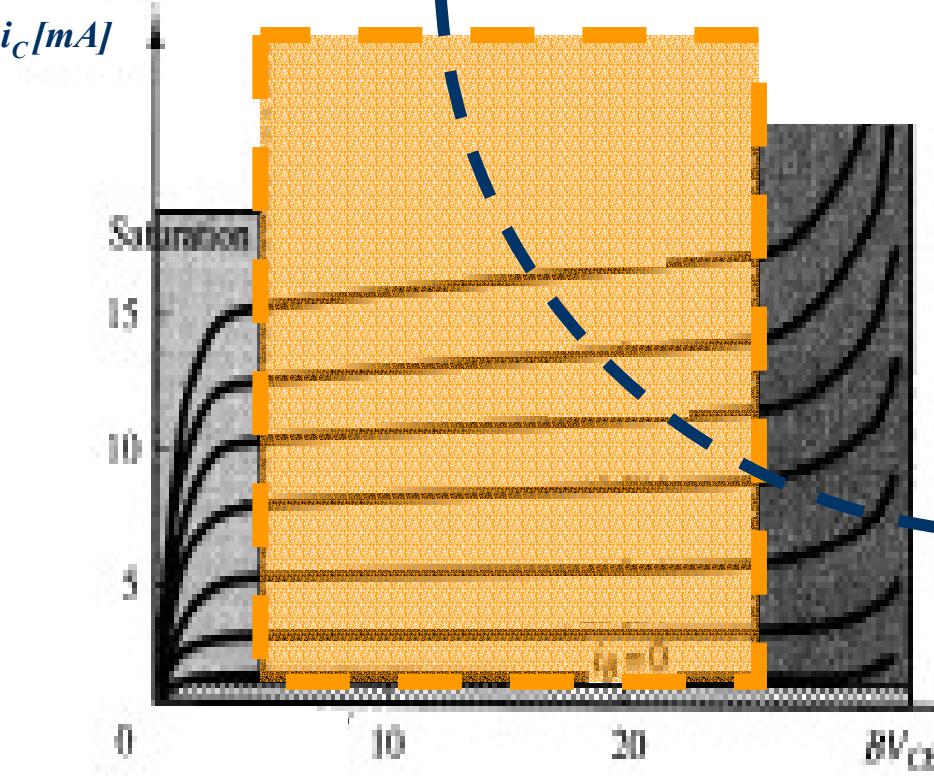
Electrónica I

FCEIA - UNR

Punto de Trabajo

Zona Activa

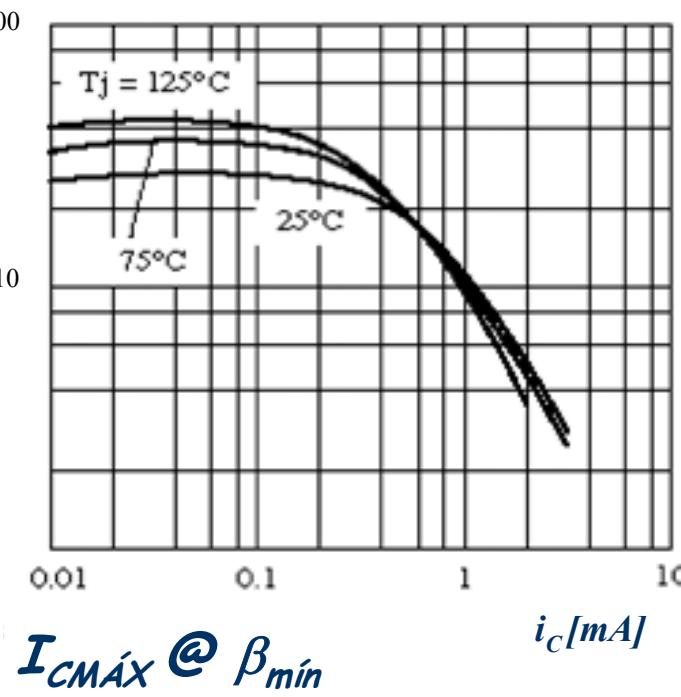
$$J_{BE} \text{ PD} - J_{CB} \text{ PI}$$



Estable e independiente
de la dispersión
de los parámetros

Mínima disipación de
potencia

Compatible con la excursión de
señal de salida requerida



BJT polarizado

Punto de Trabajo

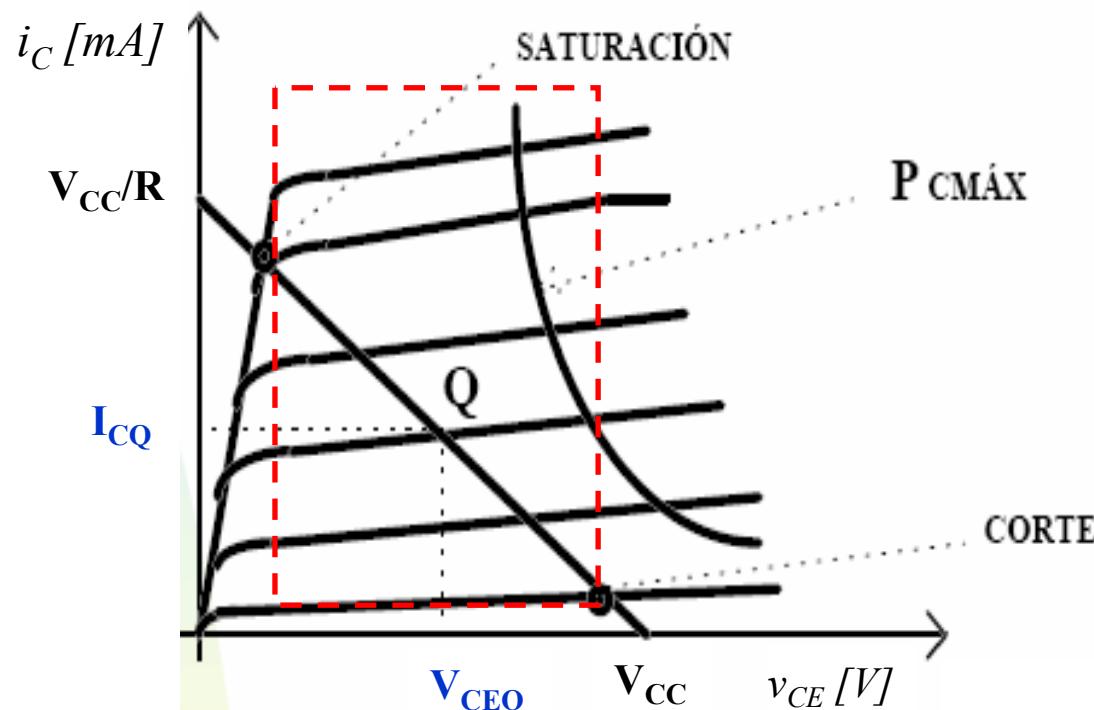
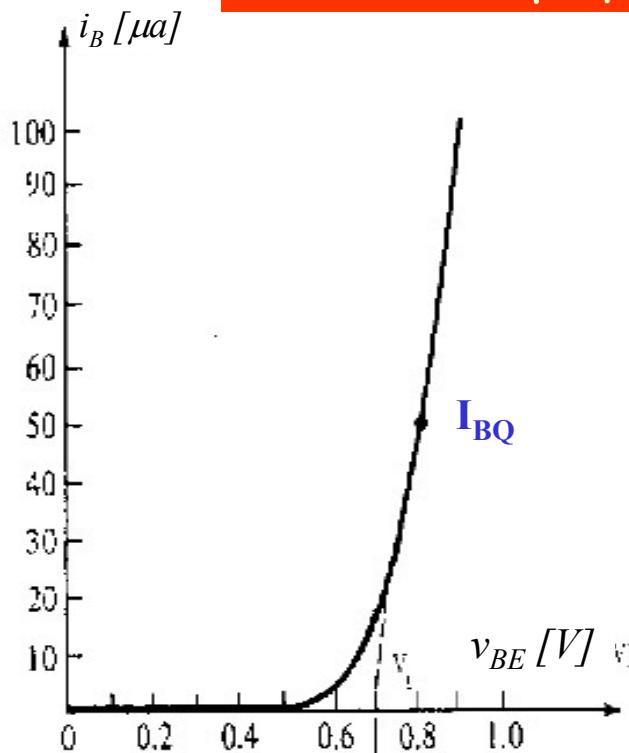
I_{CQ} V_{CEQ}

modelo lineal
para el BJT

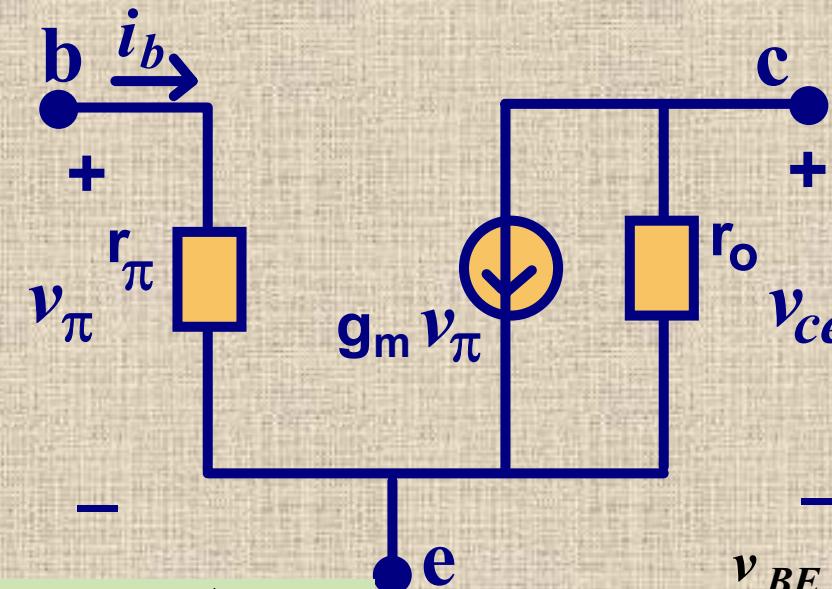
Superposición
condicionada alrededor
del punto de trabajo

BJT funciona
linealmente

modelo en pequeña señal



modelo BJT en pequeña señal



$$r_o = \frac{v_{ce}}{i_c} \Big|_{V_{CEQ}}$$

$$r_o = \frac{I_{CQ}}{-V_A}$$

Tensión Early

i_c

$$i_c \approx \frac{I_{CQ}}{V_T} v_{be} = g_m v_{be} \Leftrightarrow g_m = \frac{I_{CQ}}{V_T}$$

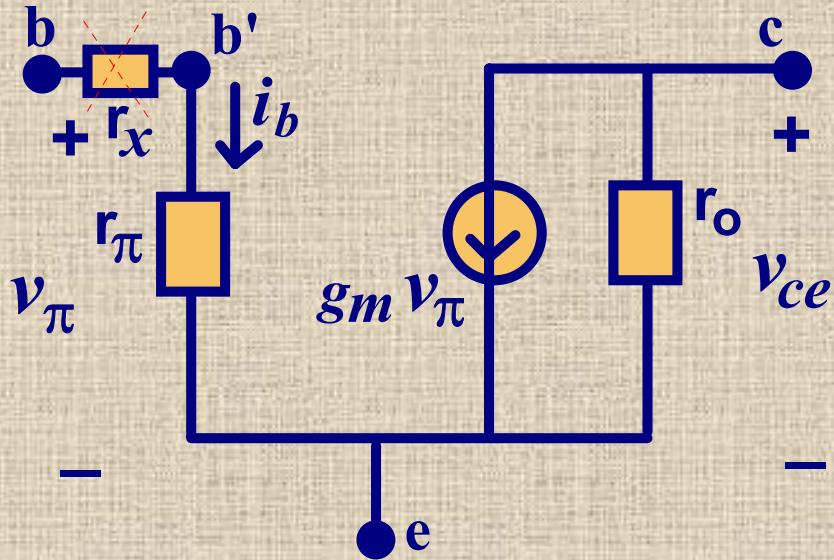
$$r_\pi = \left(\frac{\partial i_b}{\partial v_{be}} \right)^{-1} = \frac{v_\pi}{i_b}$$

$$g_m = \frac{\partial i_c}{\partial v_{be}} = \frac{\beta i_b}{v_{be}} = \frac{\beta}{r_\pi}$$

$$i_C \approx I_s e^{\frac{v_{BE}}{V_T}} = I_s e^{\frac{V_{BEQ} + v_{be}}{V_T}} = I_{CQ} e^{\frac{v_{be}}{V_T}}$$

$$i_C \approx I_{CQ} + \frac{I_{CQ}}{V_T} v_{be} + \frac{1}{2!} \frac{I_{CQ}}{V_T} v_{be}^2 + \dots$$

BJT en pequeña señal



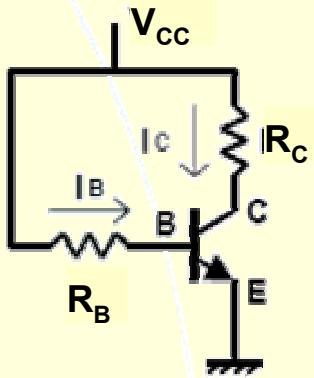
Si $I_{CQ}=1mA$ $\beta \approx 200$
 $z_i \approx 5K\Omega$ $g_m = 0,04A/V$

$$z_{i_{BJT}} = r_\pi = \frac{\beta V_T}{I_{CQ}}$$

$$g_m r_\pi = \beta$$

Si $I_{CQ}=1mA$ $V_A \approx -200V$
 $z_o \approx 200K\Omega$

$$g_m = \frac{I_{CQ}}{V_T}$$



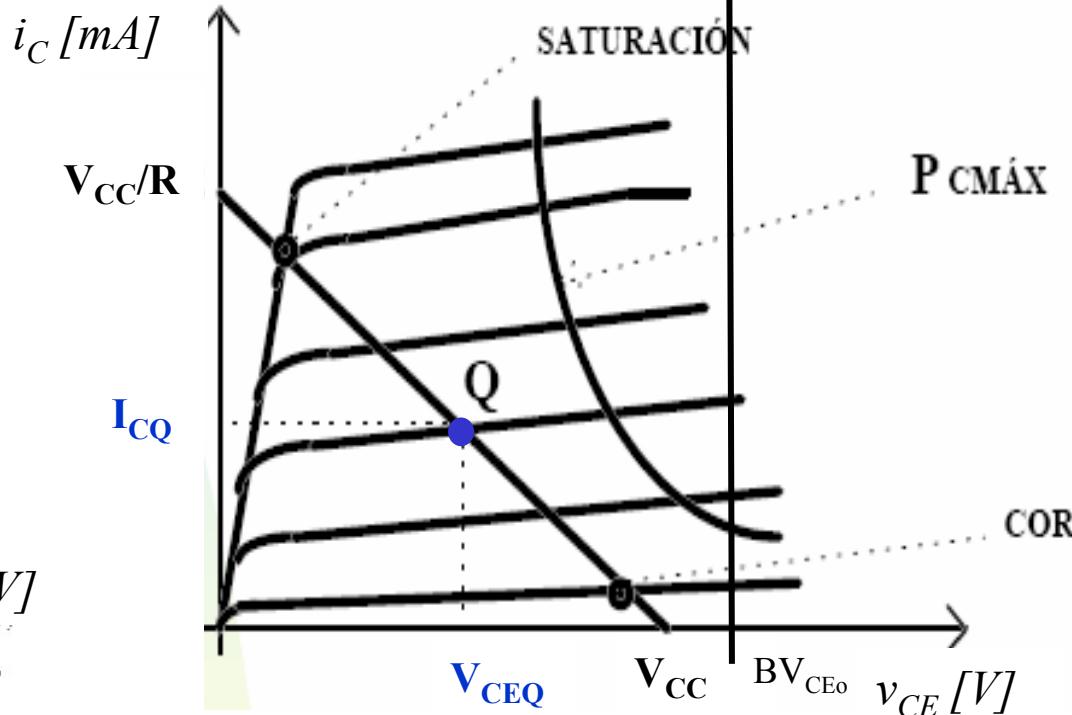
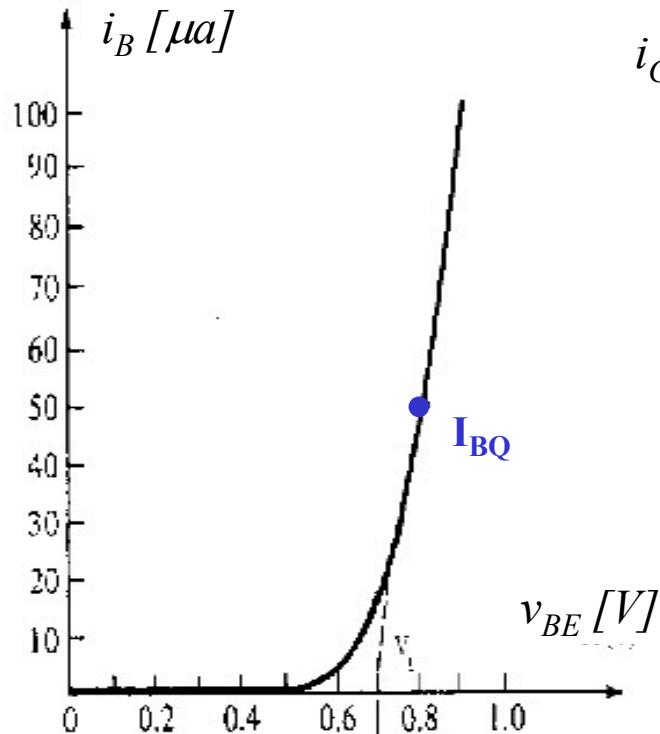
recta polarización

$$I_{B_Q} = \frac{(V_{CC} - V_{BE_Q})}{R_B}$$

recta de carga

$$I_{C_Q} = \frac{(V_{CC} - V_{CE_Q})}{R_C}$$

I_{B_Q}
 I_{C_Q}
 V_{CE_Q}



Característica de entrada

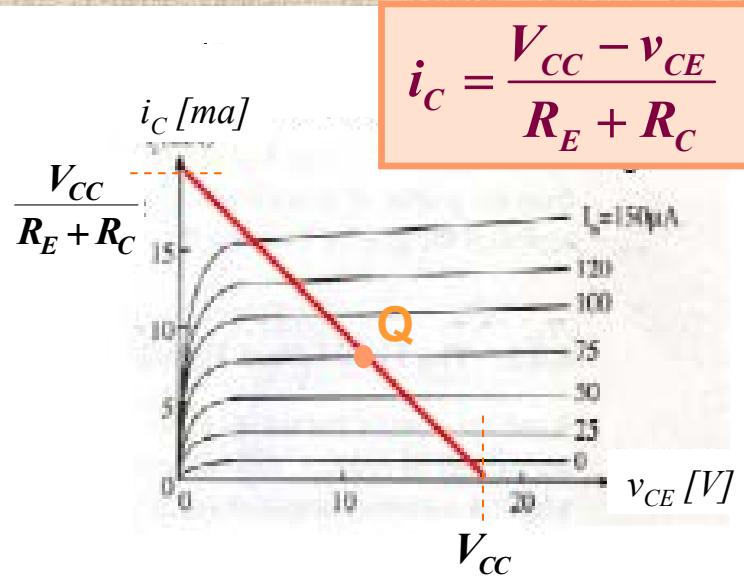
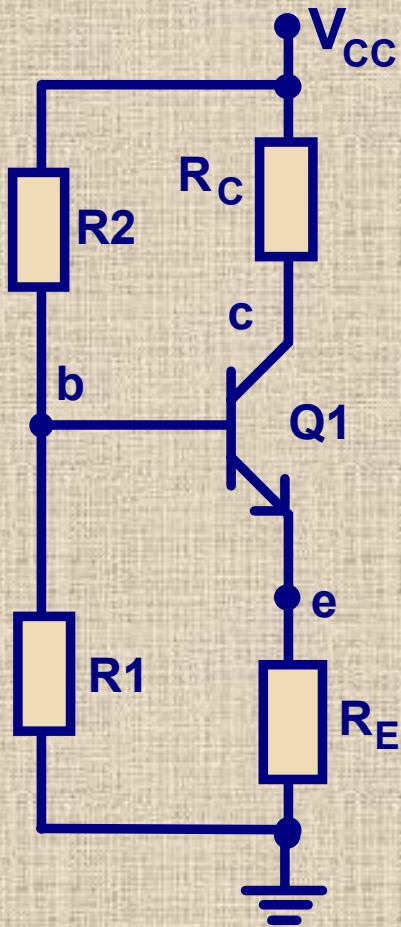
Característica de salida

El circuito fija
la corriente
de emisor

$$I_B = \frac{I_{CQ}}{\beta}$$

Zona activa

$$I_{EQ} = \frac{V_{BB} - V_{BEQ}}{R_E} \approx I_{CQ}$$

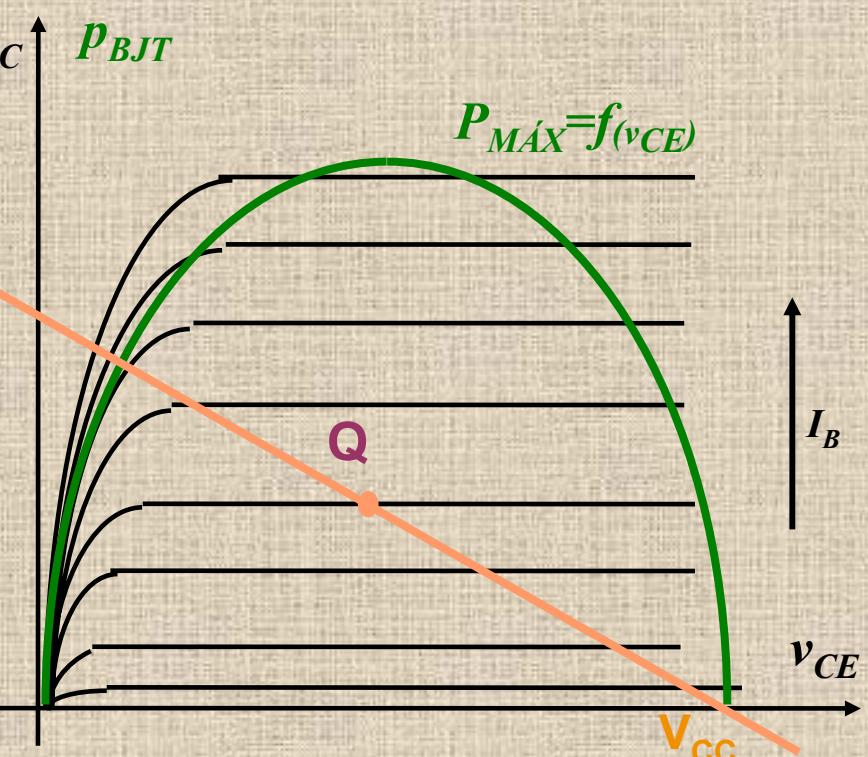


$$V_{BB} = V_{CC} \frac{R_1}{R_1 + R_2}$$

$$I_B \ll \frac{V_{CC}}{R_1 + R_2}$$

Criterios de Diseño

Selección del punto de trabajo
y elementos del circuito



$$p_{BJT} \approx i_C v_{CE} \approx \frac{V_{CC} - v_{CE}}{R_E + R_C} v_{CE}$$

Si $v_{CE} = V_{cc}/2 \Rightarrow P_{MÁX}$

*Si $v_{CE} < V_{cc}/2$
cuando I_C aumenta
 P_{BJT} disminuye*

Clase A

$V_{CEQ} \approx V_{cc}/2$

*Evita embalamiento térmico,
estabiliza punto de trabajo*

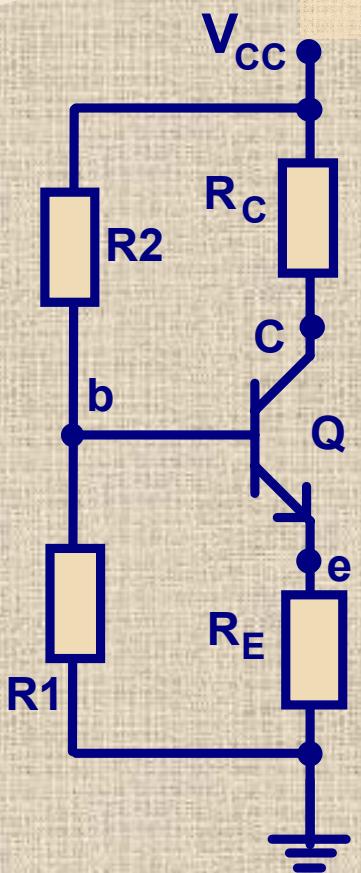
*Si $v_{CE} > V_{cc}/2$
cuando I_C aumenta
 P_{BJT} aumenta*

*Disipación de
Potencia*

JT en
zona activa

recida de carga

$$i_C = \frac{V_{CC} - v_{CE}}{R_E + R_C}$$



$$i_C = \beta i_B + (\beta + 1) I_{CO}$$

$$i_B + i_C = i_E$$

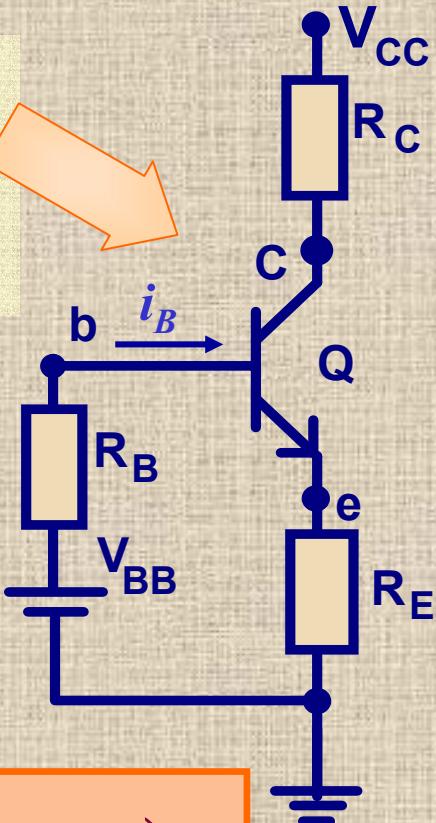
thevenin

$$R_B = R_1 // R_2$$

$$V_{BB} = \frac{V_{CC}}{R_1 + R_2} R_2$$

$$i_B R_B + i_E R_E = V_{BB} - V_{BE}$$

$$i_C = \frac{\beta (V_{BB} - V_{BE}) + (\beta + 1) I_{CO} R_B}{(\beta + 1) R_E + R_B}$$



si $\beta \gg 1$

$R_B \ll \beta R_E$

$$i_C \approx \frac{(V_{BB} - V_{BE})}{R_E}$$

Independiente
características BJT

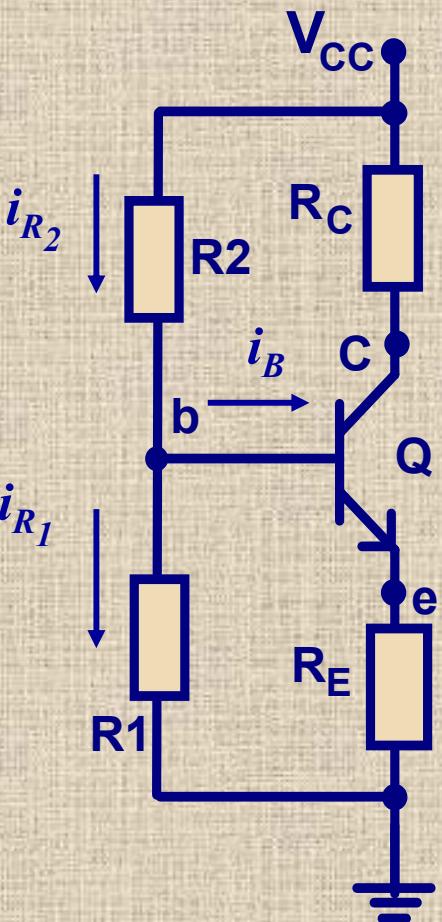
Criterios a tener en cuenta para la polarización

Elección BJT

Adopción punto de trabajo I_{CQ}

Adopción V_{CC}

$$V_{CEQ} \approx V_{CC}/2$$



$$i_{R_2} = i_B + i_{R_1} \approx i_{R_1}$$

Elegida I_{CQ} considerando $\beta_{mín}$

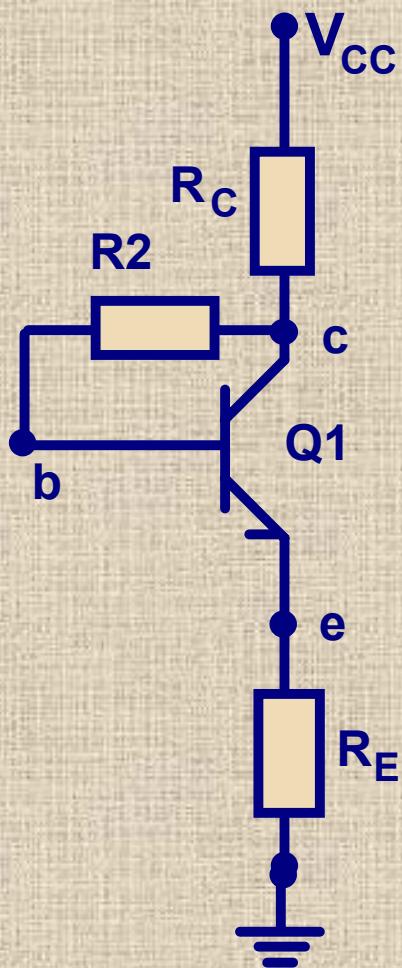
$$I_{B_Q MÁX} = I_{CQ} / \beta_{mín}$$

$$\text{si } I_{B_Q MÁX} \ll \frac{V_{CC}}{R_1 + R_2} \approx i_{R_{1,2}} \Rightarrow V_{BB} = \frac{V_{CC} R_2}{R_1 + R_2}$$

$$R_B = R_1 // R_2$$

$$R_B \ll \beta R_E$$

Otro posible
circuito



$$i_c = \frac{V_{CC} - v_{CE}}{R_E + R_C}$$

$$i_C = \beta i_B + (\beta + 1) I_{CO}$$

$$i_c = \frac{\beta}{\beta + 1} i_E$$

$$i_c = \frac{\beta(V_{CC} - V_{BE}) + I_{CO}(\beta + 1)R_2}{R_2 + \beta(R_C + R_E)}$$

Para independencia
del β

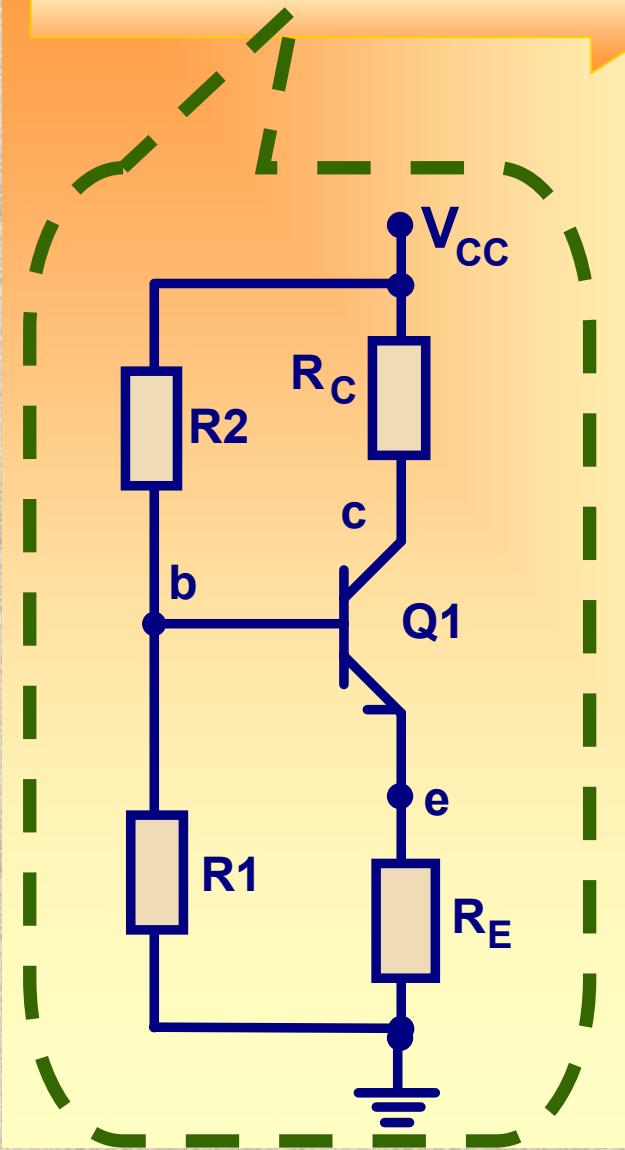
$$R_2 \ll \beta(R_C + R_E)$$

Difícil cumplimiento

$$R_2 \approx \beta(R_C + R_E)$$

BJT Polarizado

Etapas amplificadoras básicas



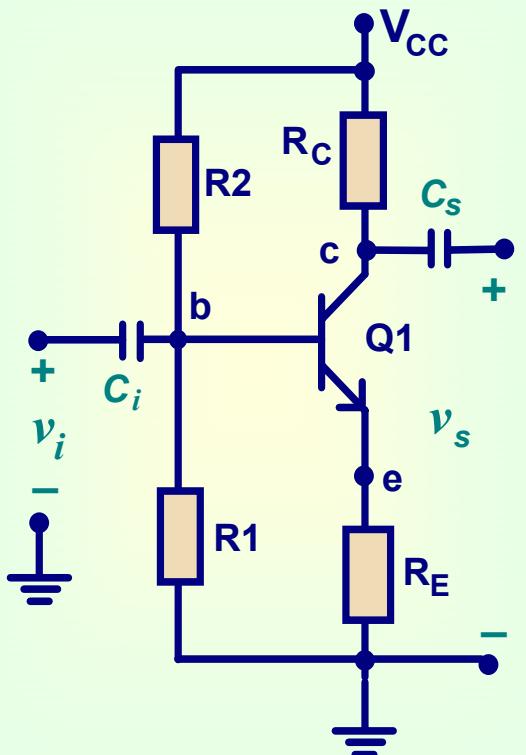
terminal de excitación
terminal de salida

Terminal
común

emisor común
base común
colector común

Etapas básicas amplificadoras

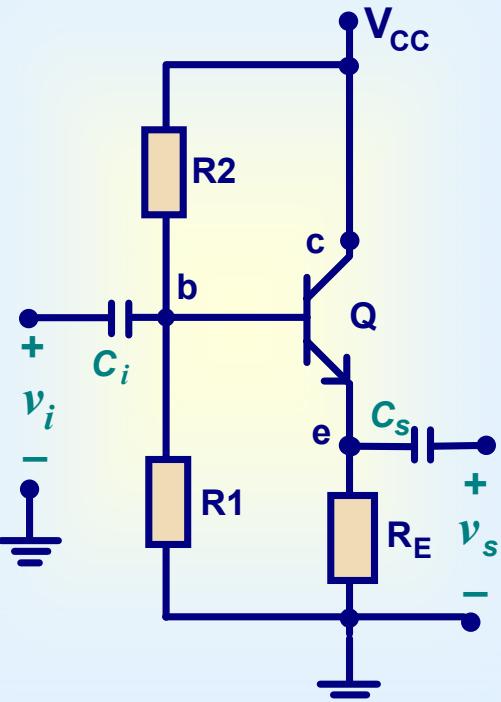
emisor común



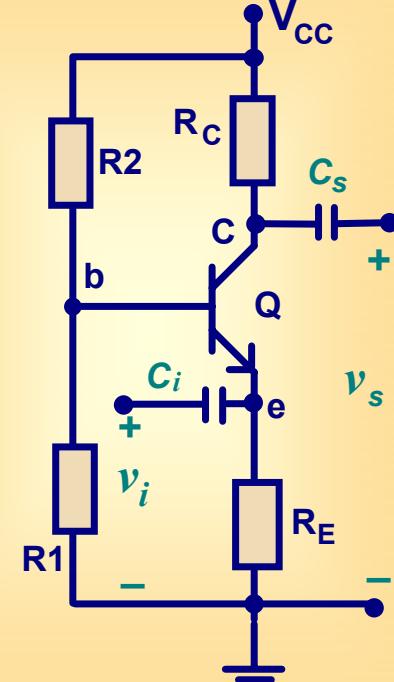
$$A_v = \frac{v_o}{v_i}$$

$$A_i = \frac{i_o}{i_i}$$

colector común

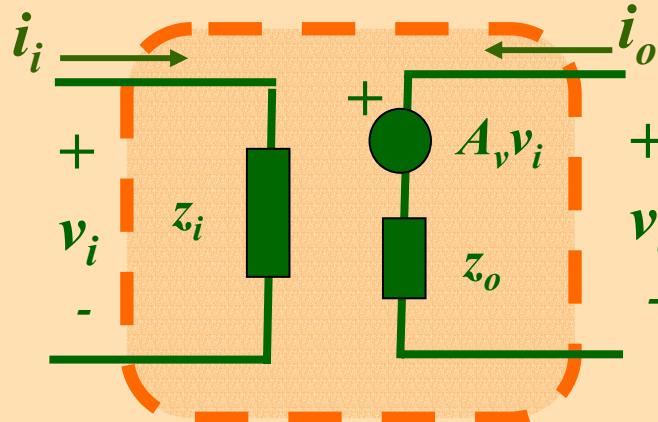


base común

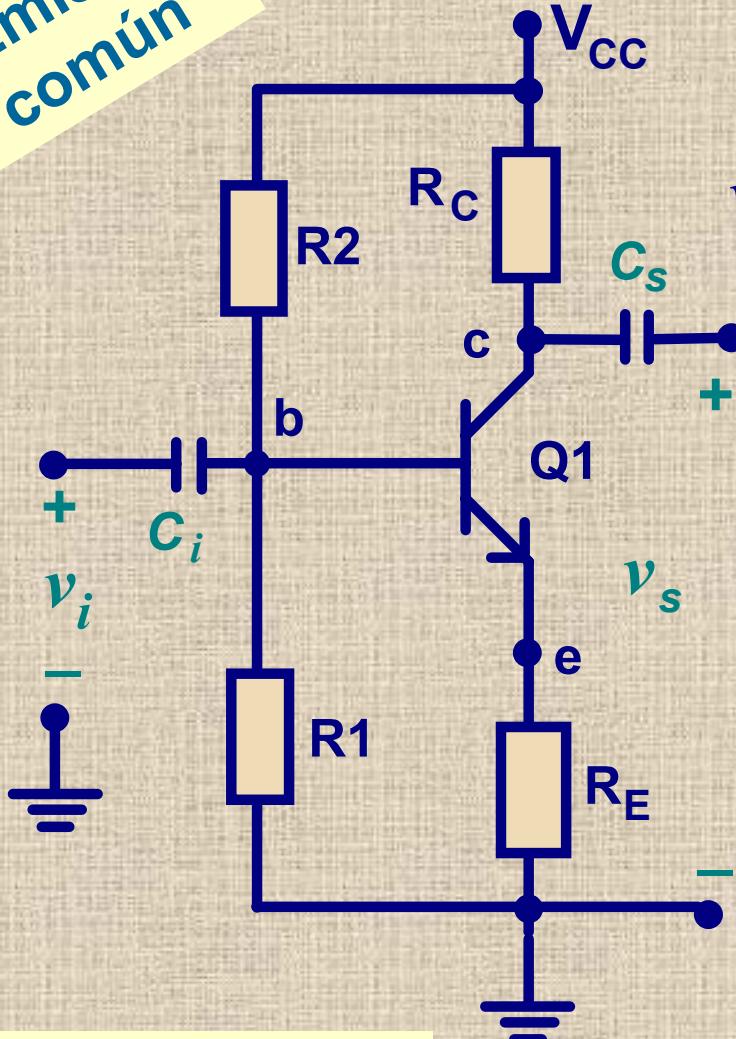


$$z_i = \frac{v_i}{i_i}$$

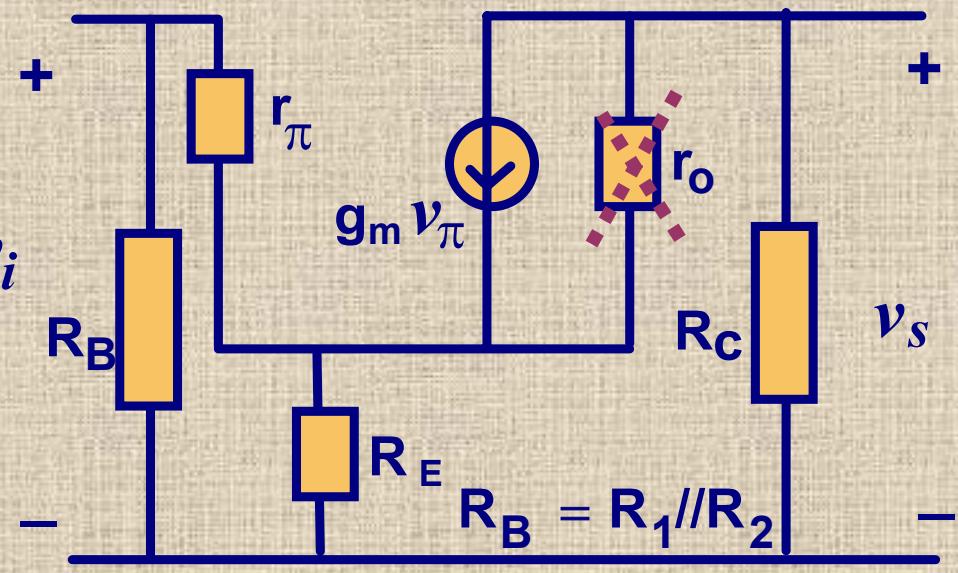
$$z_o = \frac{v_o}{i_o} \Big|_{v_i=0}$$



Emisor común



$$z_o = \left. \frac{v_s}{i_s} \right|_{v_i=0} \approx R_C$$



$$i_c = \frac{v_{ce}}{r_o} + g_m v_{\pi}$$

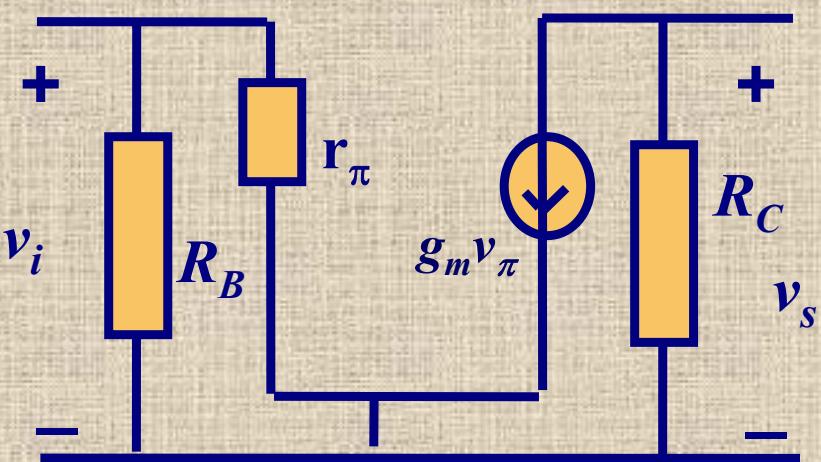
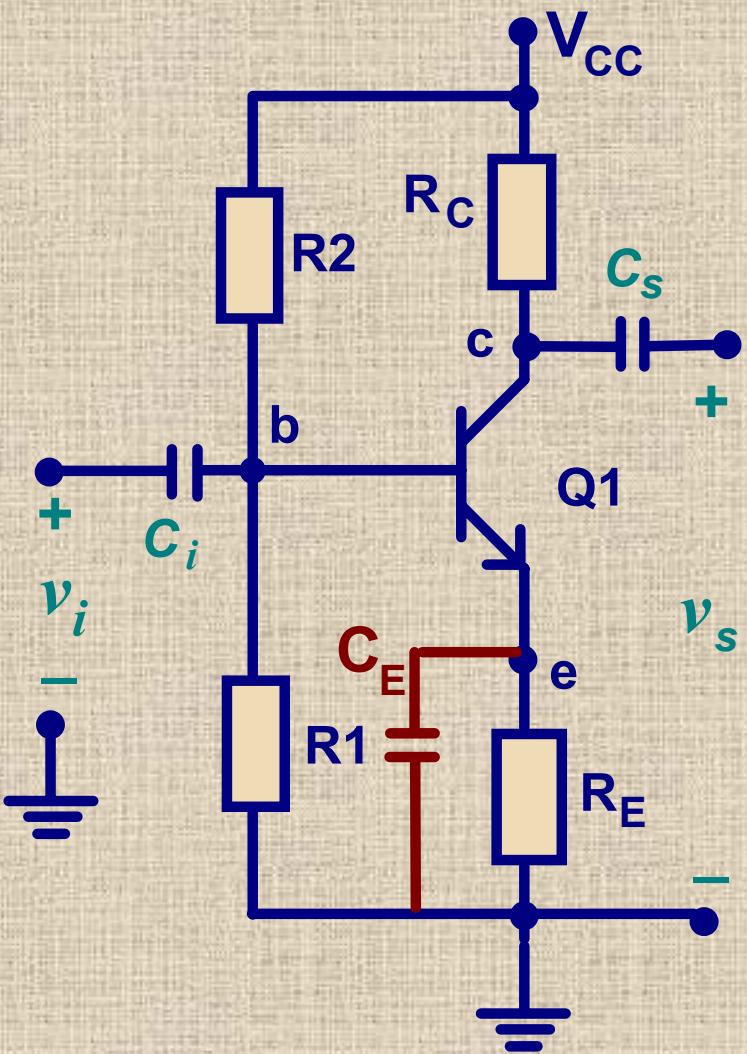
$$v_{\pi} = v_i - i_c R_E$$

$$v_o = -i_c R_C$$

$$A_v \approx -\frac{g_m R_C}{1 + g_m R_E} \approx -\frac{R_C}{R_E}$$

$$z_i \approx R_B // r_{\pi} (1 + g_m R_E) \approx R_B$$

Emisor común con capacitor de emisor

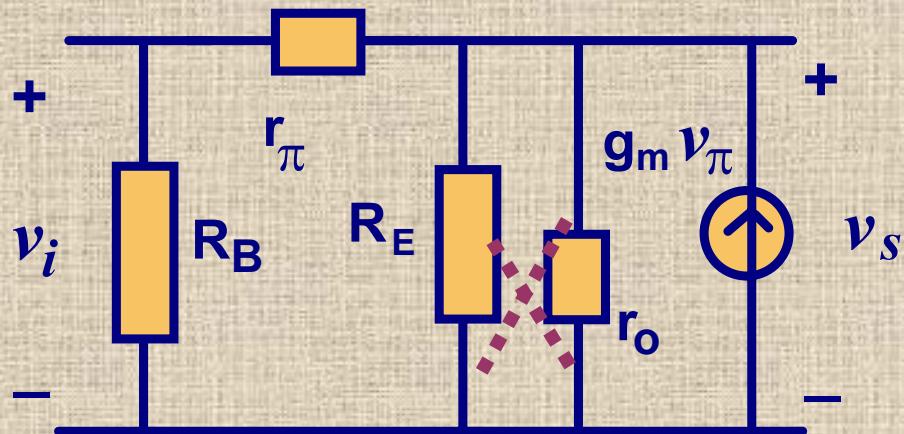
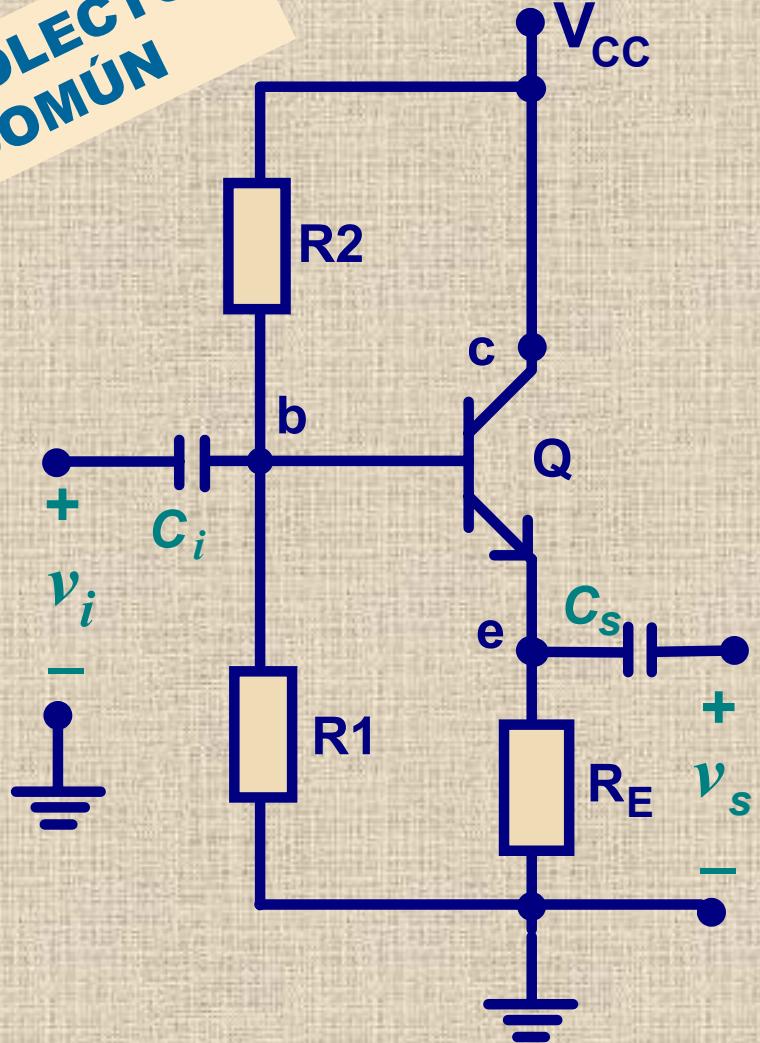


$$A_v \approx -g_m R_c$$

$$z_i \approx R_B // r_\pi \approx r_\pi$$

$$z_o \approx R_C$$

COLECTOR COMÚN



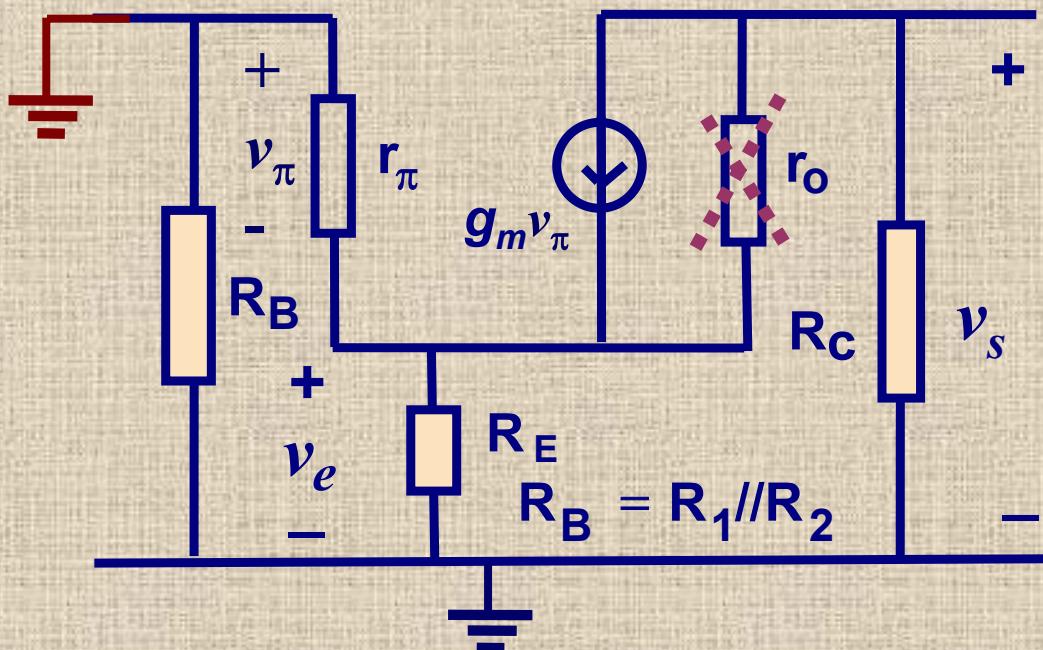
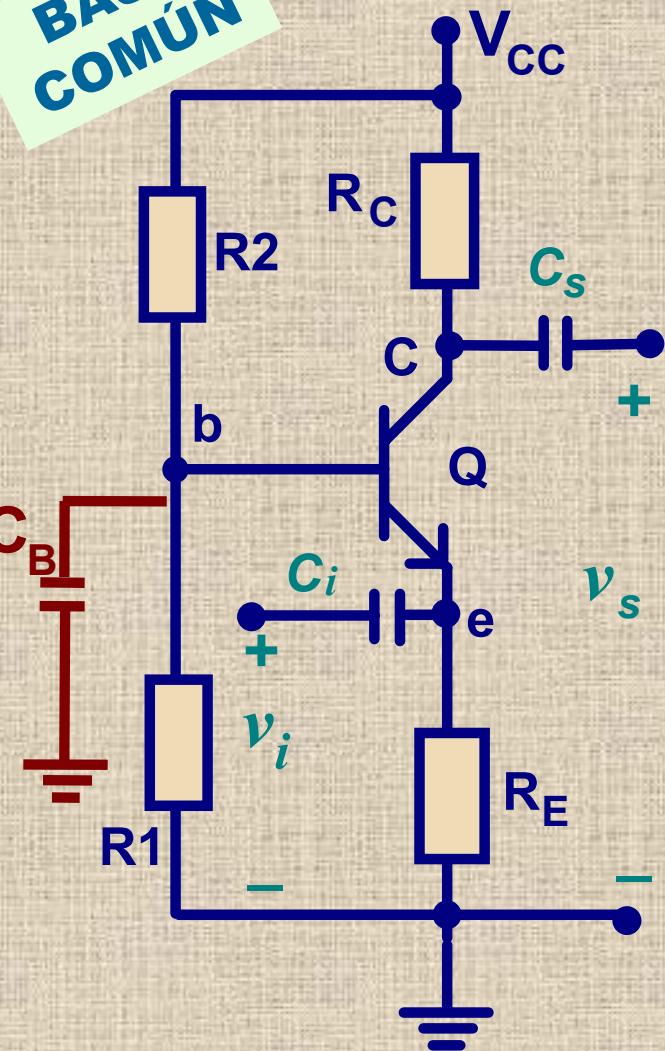
$$z_i = \frac{v_i}{i_i} \approx R_B // r_\pi (1 + g_m R_E)$$

$$z_i \approx R_B // \beta R_E \approx R_B$$

$$z_o = \left. \frac{v_o}{i_s} \right|_{v_i=0} \approx r_\pi // R_E // \frac{1}{g_m} \approx g_m^{-1}$$

$$A_v = \frac{v_s}{i_i} \approx \frac{R_E (1 + g_m r_\pi)}{r_\pi + R_E (1 + g_m r_\pi)} \approx \frac{g_m R_E}{1 + g_m R_E} \approx 1$$

**BASE
COMÚN**



$$A_v \approx g_m R_c \frac{r_\pi}{r_\pi + R_B} \approx g_m R_c$$

$$A_i \approx 1$$

$$z_i ; R_E // \frac{r_\pi + R_B}{1 + g_m r_\pi} \approx \frac{r_\pi + R_B}{1 + \beta} \approx g_m^{-1}$$

Si R_s = resistencia generador
 z_o depende de R_s

$$z_o = r_o \left(1 + g_m r_\pi \frac{R_E^*}{r_\pi + R_B} \right)$$

$$R_E^* = R_s // R_E // (r_\pi + R_B) \\ z_o = r_o \left(1 + g_m R_E \right)$$

ec

$$A_v \approx -\frac{g_m R_C}{1 + g_m R_E} \approx -\frac{R_C}{R_E}$$

$$z_i \approx R_B // r_\pi (1 + g_m R_E)$$

$$z_i \approx R_B$$

$$z_o \approx R_C$$

**amplificador
de tensión
y corriente**

$$z_i \approx R_B // \beta R_E \approx R_B$$

$$A_v = \frac{v_s}{v_e} \approx 1$$

$$z_o \approx r_\pi // R_E // \frac{1}{g_m} \approx g_m^{-1}$$

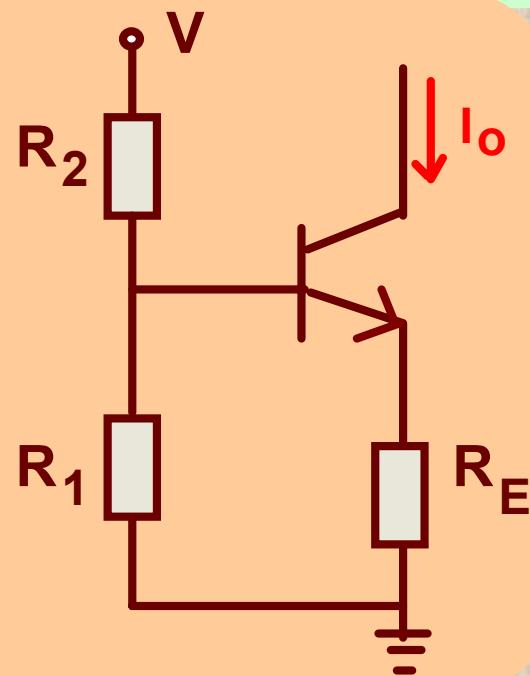
**adaptador de impedancia
amplifica corriente**

bc

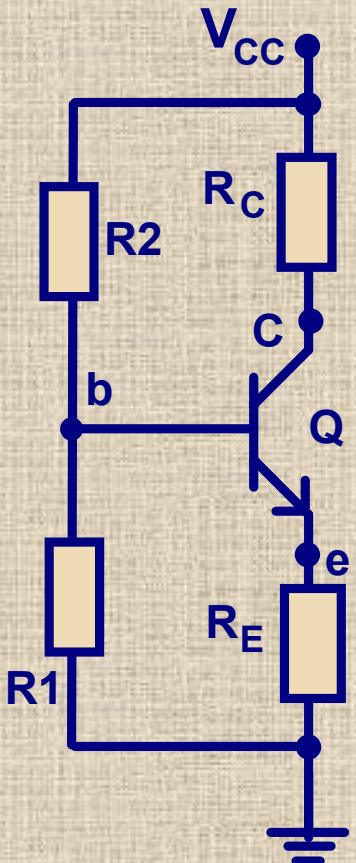
$$I_o = \frac{V_{BB} - V_{BE}}{R_E}$$

$$z_o \approx r_o (1 + g_m R_E)$$

**fuente de
corriente o
carga activa**



Otros criterios a tener en cuenta



ec

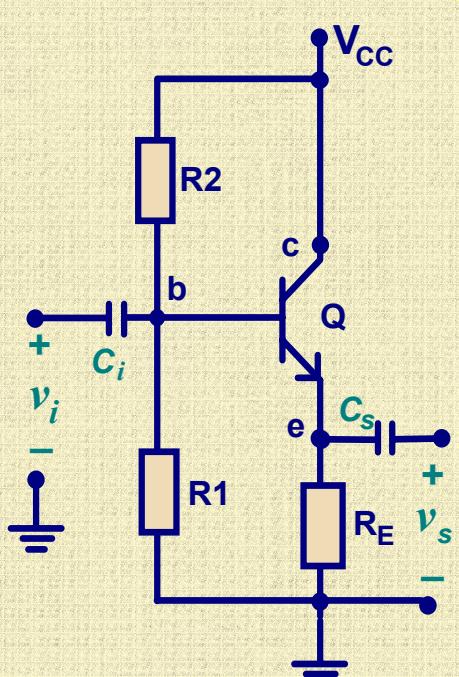
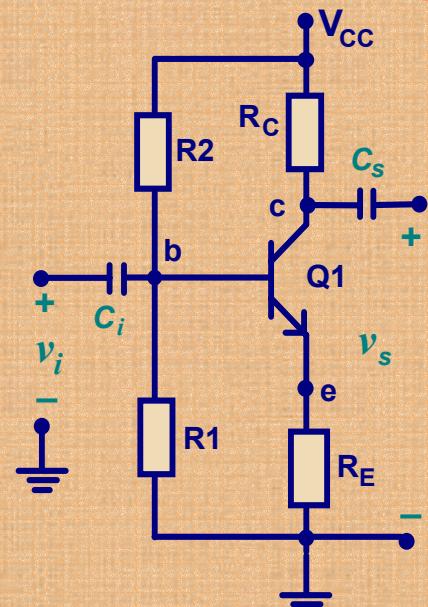
$$A_v \approx -\frac{R_C}{R_E}$$

$$R_E < R_C$$

$$z_i = R_1 // R_2 \approx R_B$$

cc

$$R_C = 0$$



BJT Polarizado FET Polarizado

BJT
emisor común
base común
colector común

terminal de excitación
terminal de salida

Etapas amplificadoras básicas

FET
fuente común
puerta común
drenaje común

Terminal común

ec**emisor común****sc****fuente común**

$$A_v \approx -\frac{g_m R_c}{1 + g_m R_E} \approx -\frac{R_c}{R_E}$$

$$z_i \approx R_B // r_\pi (1 + g_m R_E) \approx R_B$$

$$z_o = \left. \frac{v_s}{i_s} \right|_{v_i=0} \approx R_C$$

$$A_v = \frac{v_o}{v_i} \approx \frac{-g_m R_D}{1 + g_m R_S}$$

$$z_i = R_G // z_{iFET} \approx R_G$$

$$z_o \equiv \left. \frac{v_o}{i_o} \right|_{e_i=0} \approx R_D$$

Amplificador de tensión

cc**colector común****dc****drenaje común**

$$A_v \approx \frac{g_m R_E}{1 + g_m R_E} \approx 1$$

$$z_i \approx R_B // \beta R_E \approx R_B$$

$$z_o \approx g_m^{-1}$$

$$A_v \approx \frac{g_m R_S}{1 + g_m R_S} < 1$$

$$z_i = R_G = R_1 // R_2$$

$$z_o \approx g_m^{-1}$$

Adaptador de impedancia**amplifica corriente**

bc

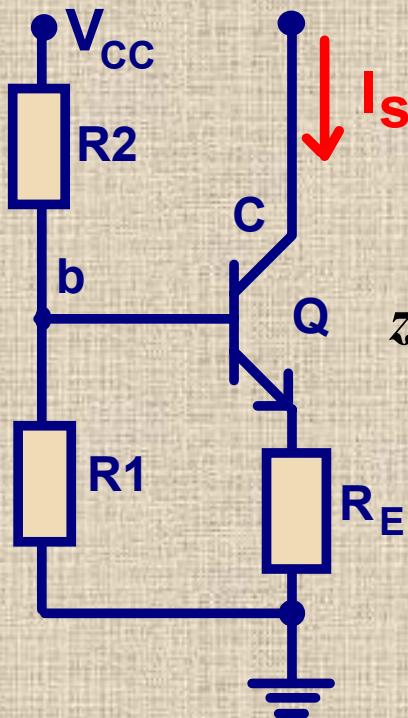
$$A_v \approx g_m R_C \frac{r_\pi}{r_\pi + R_B}$$

$$z_i \approx \frac{r_\pi + R_B}{1 + \beta}$$

gc

$$z_i = g_m^{-1} // R_S \approx g_m^{-1}$$

**fuente de corriente
o carga activa**

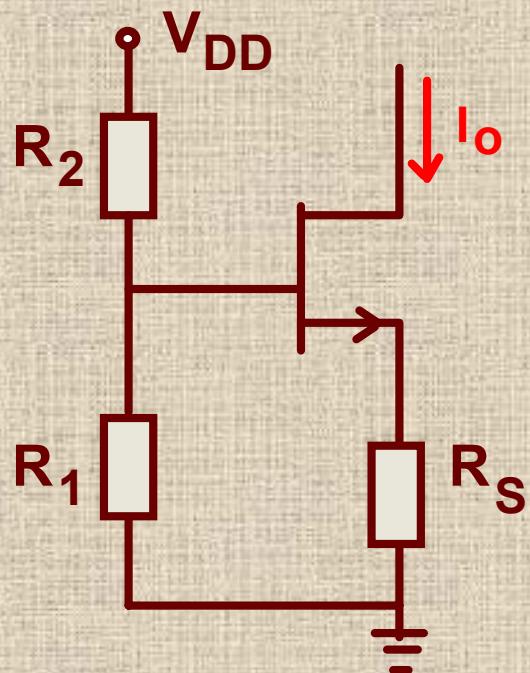


$$I_s \approx \frac{V_{BB} - V_{BE}}{R_E}$$

$$z_o \approx r_o \left(1 + \frac{g_m r_\pi R_E}{r_\pi + R_B + R_E} \right)$$

R1 puede ser
reemplazada
por un zener

base común



$$z_o \approx r_o (1 + g_m R_S)$$

puerta común